

HD74LVCR2245A

Octal Bidirectional Transceivers with 3-state Outputs

REJ03D0377-0400
(Previous ADE-205-235B (Z))
Rev.4.00
Aug. 20, 2004

Description

The HD74LVCR2245A has eight buffers with three state outputs in a 20 pin package. When (T / \bar{R}) is high, data flows from the A inputs to the B outputs, and when (T / \bar{R}) is low, data flows from the B inputs to the A outputs. A and B bus are separated by making enable input (\overline{OE}) high level.

All outputs, which are designed to sink up to 12mA, include equivalent 26 Ω resistors to reduce overshoot and undershoot.

Low voltage and high-speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65$ to 5.5 V
- All inputs V_{IH} (Max) = 5.5 V (@ $V_{CC} = 0$ to 5.5 V)
- All inputs / outputs $V_{I/O}$ (Max) = 5.5 V (@ $V_{CC} = 0$ V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot > 2.0 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ\text{C}$)
- High output current $\pm 12\text{mA}$ (@ $V_{CC} = 3.0$ to 5.5 V)
- All outputs have equivalent 26 Ω series resistors, so no external resistors are required
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVCR2245AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)
HD74LVCR2245ATELL	TSSOP-20 pin	TTP-20DAV	T	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs

\overline{OE}	T / \bar{R}	Operation
L	L	B data to A bus
L	H	A data to B bus
H	X	Z

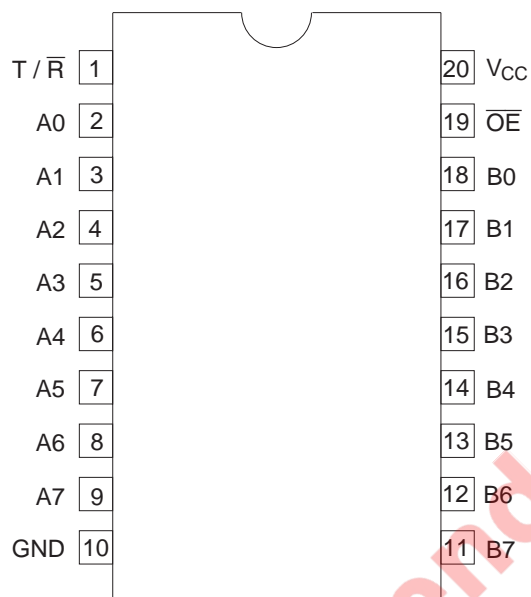
H: High level

L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement



(Top view)

Absolute Maximum Ratings

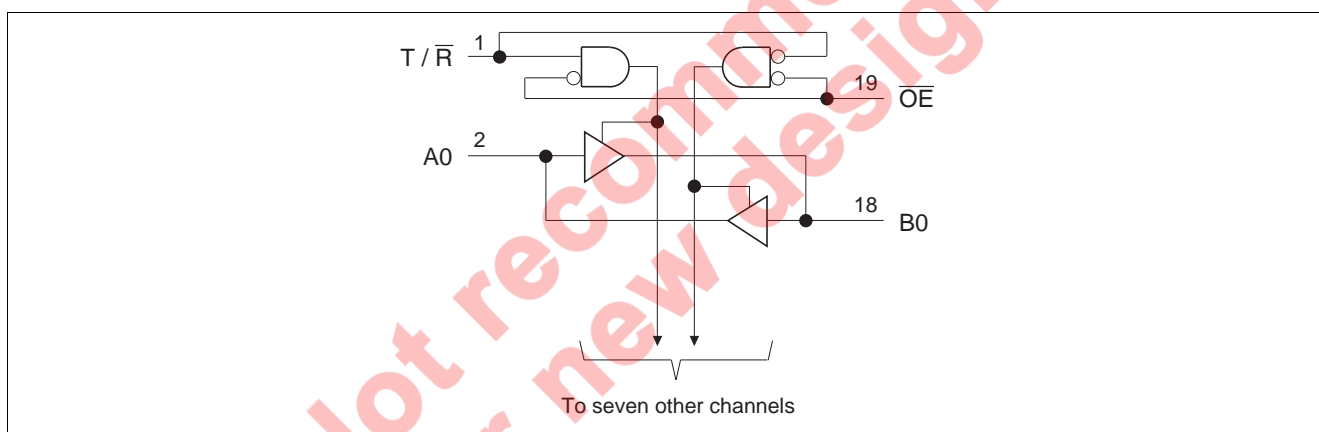
Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	-0.5 to 7.0	V	
Input voltage	V_I	-0.5 to 7.0	V	
Output voltage	V_O	-0.5 to 7.0	V	Output "Z" or V_{CC} : OFF
		-0.5 to $V_{CC}+0.5$		Output "H" or "L"
Input diode current	I_{IK}	-50	mA	$V_I < 0$
Output diode current	I_{OK}	-50	mA	$V_O < 0$
Output current	I_O	± 50	mA	
V_{CC} , GND current	I_{CC} or I_{GND}	± 100	mA	
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	1.65 to 5.5	V	At operation
		1.5 to 5.5		Data retention only
Input voltage	V_I	0 to 5.5	V	
Output voltage	V_O	0 to 5.5	V	Output "Z" or V_{CC} : OFF
		0 to V_{CC}		Output "H" or "L"
Output current	I_{OH}	-2	mA	$V_{CC} = 1.65\text{ V}$
		-4		$V_{CC} = 2.3\text{ V}$
		-8		$V_{CC} = 2.7\text{ V}$
		-12		$V_{CC} = 3.0\text{ to }5.5\text{ V}$
	I_{OL}	2	mA	$V_{CC} = 1.65\text{ V}$
		4		$V_{CC} = 2.3\text{ V}$
		8		$V_{CC} = 2.7\text{ V}$
		12		$V_{CC} = 3.0\text{ to }5.5\text{ V}$
Input rise / fall time	t_r, t_f	0 to 6	ns / V	
Operating temperature	T_a	-40 to +85	°C	

Logic Diagram



Electrical Characteristics

(Ta = -40 to 85°C)

Item	Symbol	V _{CC} (V)	Min	Typ	Max	Unit	Test Conditions
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	—	—	V	
		2.3 to 2.7	1.7	—	—		
		2.7 to 3.6	2.0	—	—		
		4.5 to 5.5	V _{CC} ×0.7	—	—		
	V _{IL}	1.65 to 1.95	—	—	V _{CC} ×0.35	V	
		2.3 to 2.7	—	—	0.7		
		2.7 to 3.6	—	—	0.8		
		4.5 to 5.5	—	—	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.2	—	—	V	I _{OH} = -100 μA
		1.65	1.2	—	—		I _{OH} = -2 mA
		2.3	1.7	—	—		I _{OH} = -4 mA
		2.7	2.2	—	—		
		3.0	2.4	—	—		I _{OH} = -6 mA
		2.7	2.0	—	—		I _{OH} = -8 mA
		3.0	2.0	—	—		I _{OH} = -12 mA
		4.5	3.6	—	—		
	V _{OL}	1.65 to 5.5	—	—	0.2	V	I _{OL} = 100 μA
		1.65	—	—	0.45		I _{OL} = 2 mA
		2.3	—	—	0.7		I _{OL} = 4 mA
		2.7	—	—	0.4		
		3.0	—	—	0.55		I _{OL} = 6 mA
		2.7	—	—	0.6		I _{OL} = 8 mA
		3.0	—	—	0.8		I _{OL} = 12 mA
		4.5	—	—	0.8		
Input current	I _{IN}	0 to 5.5	—	—	±5	μA	V _{IN} = 0 to 5.5 V
Off state output current	I _{OZ}	1.65 to 5.5	—	—	±5	μA	V _{OUT} = 0 to 5.5 V
Output leak current	I _{OFF}	0	—	—	±5	μA	V _{IN} or V _O = 5.5 V
Quiescent supply current	I _{CC}	1.65 to 3.6	—	—	10	μA	V _{IN} = 3.6 to 5.5 V ^{*1} , I _O = 0
		1.65 to 5.5	—	—	10		V _{IN} = V _{CC} or GND
	ΔI _{CC}	2.7 to 3.6	—	—	500	μA	V _{IN} = one input at (V _{CC} -0.6)V, other inputs at V _{CC} or GND
Input capacitance	C _{IN}	3.3	—	3.4	—	pF	V _{IN} = V _{CC} or GND
Input output capacitance	C _{I/O}	3.3	—	9.5	—	pF	V _{OUT} = V _{CC} or GND

Note: 1. This applies in the disabled state only.

Switching Characteristics

(Ta = -40 to 85°C)

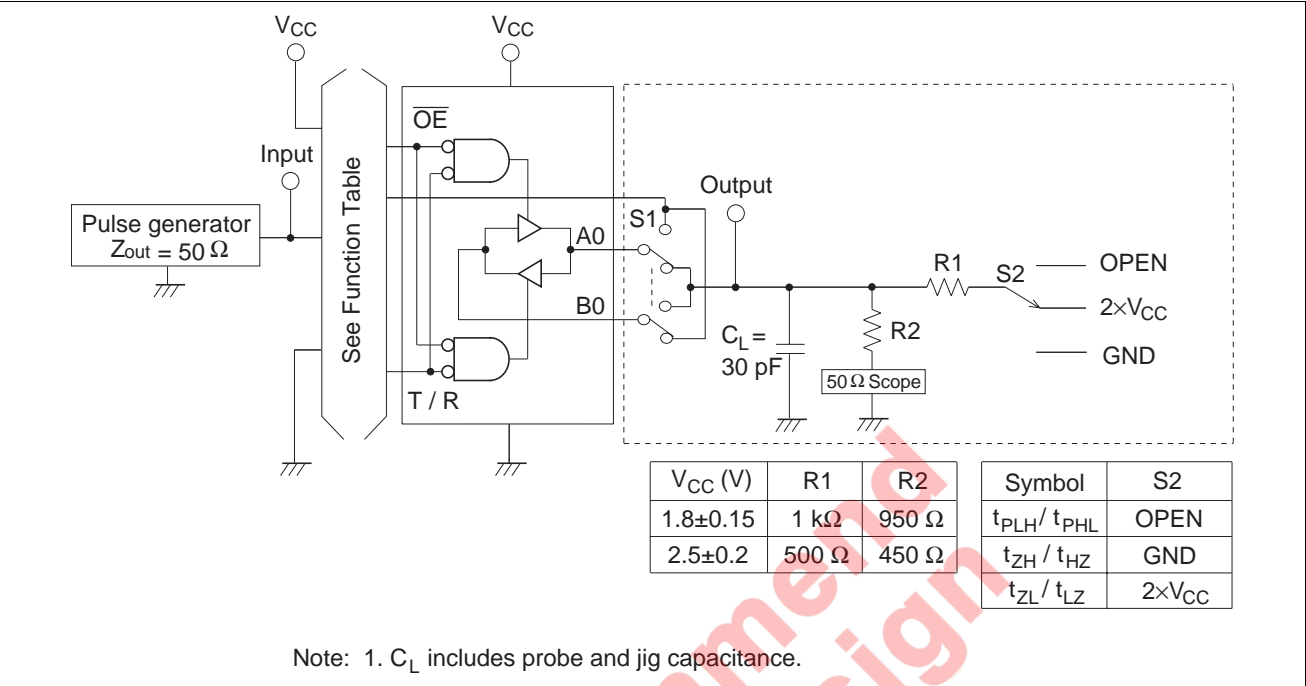
Item	Symbol	V _{CC} (V)	Min	Typ	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH}	1.8±0.15	—	—	15.0	ns	A or B	B or A
	t _{PHL}	2.5±0.2	—	—	9.0			
		2.7	—	—	7.3			
		3.3±0.3	1.5	—	6.3			
		5.0±0.5	—	—	4.8			
Output enable time	t _{ZH}	1.8±0.15	—	—	18.0	ns	OE	A or B
	t _{ZL}	2.5±0.2	—	—	11.0			
		2.7	—	—	9.5			
		3.3±0.3	1.5	—	8.2			
		5.0±0.5	—	—	6.8			
Output disable time	t _{HZ}	1.8±0.15	—	—	16.0	ns	OE	A or B
	t _{LZ}	2.5±0.2	—	—	10.0			
		2.7	—	—	8.5			
		3.3±0.3	1.7	—	7.8			
		5.0±0.5	—	—	6.6			
Between output pin skew ^{*1}	t _{OSLH}	1.8±0.15	—	—	2.0	ns		
	t _{OSHL}	2.5±0.2	—	—	2.0			
		2.7	—	—	1.5			
		3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0			

Note: 1. This parameter is characterized but not tested.

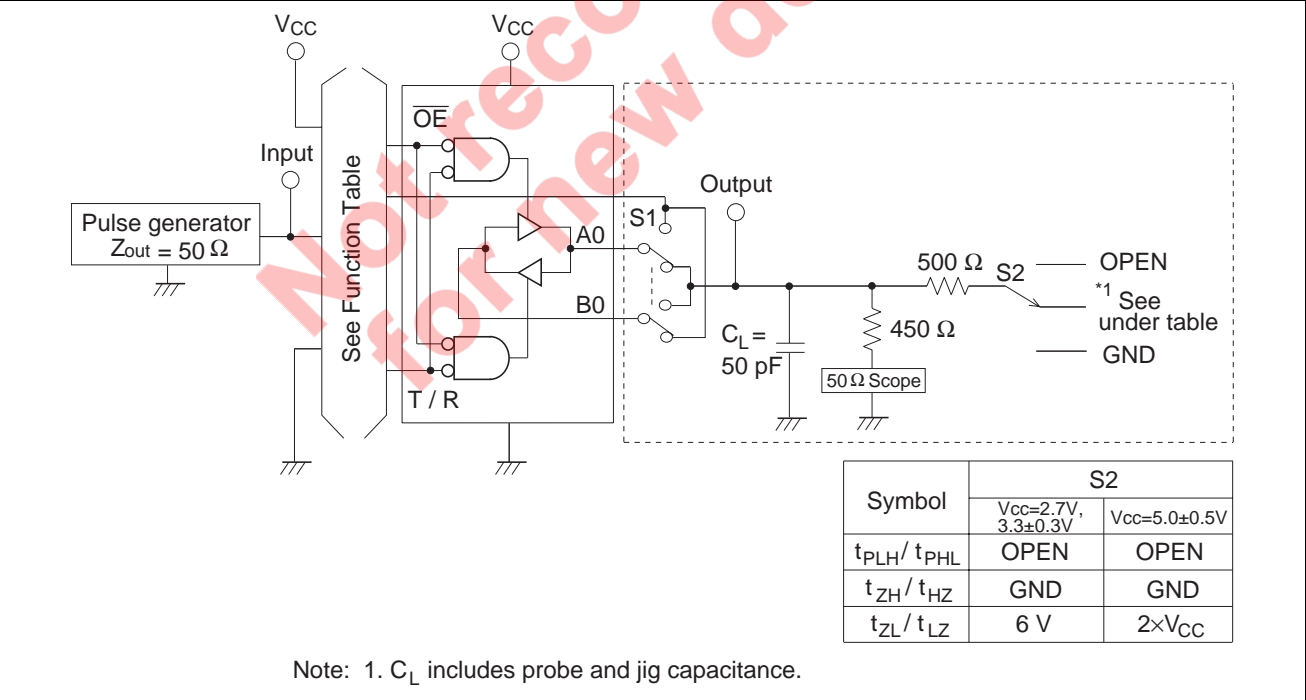
$$t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$$

Test Circuit

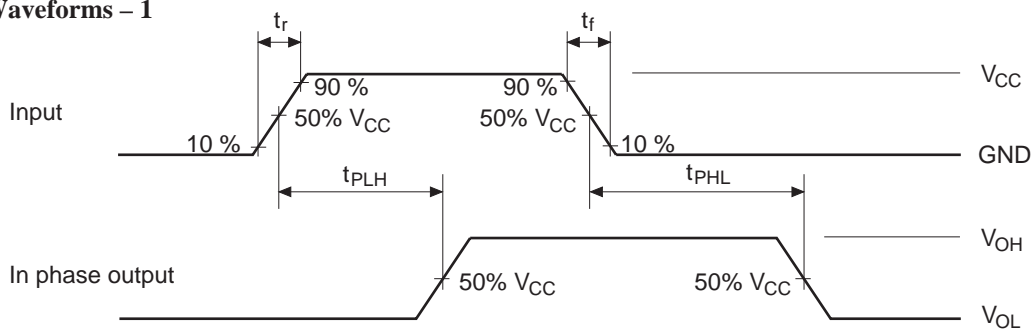
($V_{CC} = 1.8 \pm 0.15 \text{ V}$, $V_{CC} = 2.5 \pm 0.2 \text{ V}$)



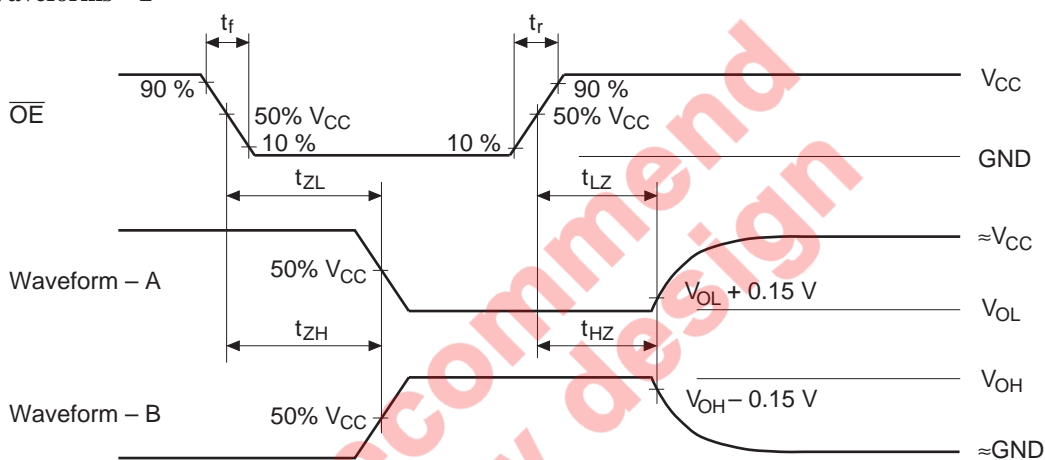
($V_{CC} = 2.7 \text{ V}$, $V_{CC} = 3.3 \pm 0.3 \text{ V}$, $V_{CC} = 5.0 \pm 0.5 \text{ V}$)



• Waveforms – 1

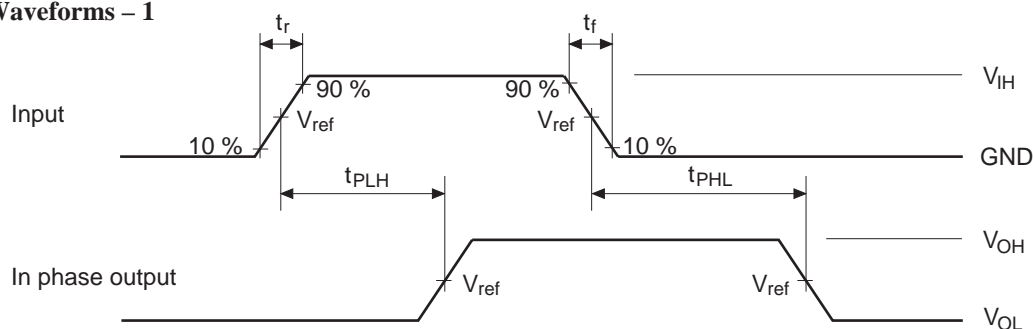


• Waveforms – 2

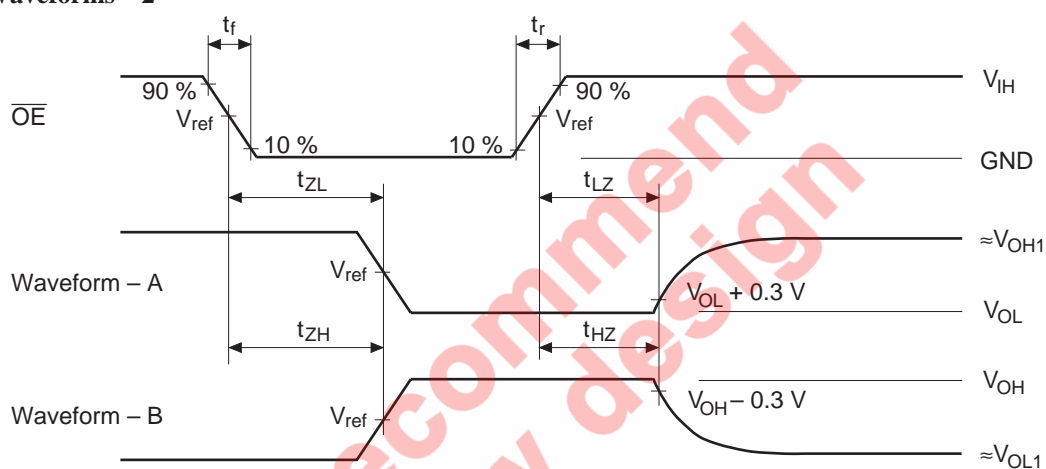


- Notes:
1. Input waveform : PRR = 10 MHz, duty cycle 50%, $t_r = 2.0 \text{ ns}$, $t_f = 2.0 \text{ ns}$
 2. Waveform – A shows input conditions such that the output is "L" level when enabled by the output control.
 3. Waveform – B shows input conditions such that the output is "H" level when enabled by the output control.

• Waveforms – 1



• Waveforms – 2



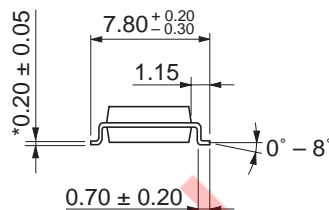
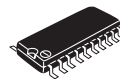
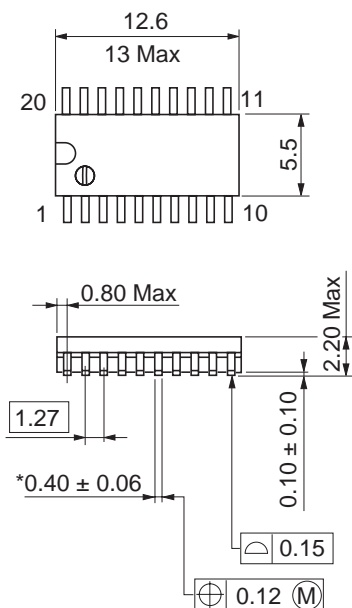
TEST	V _{CC} =2.7V 3.3±0.3V	V _{CC} =5.0±0.5V
V _{IH}	2.7 V	V _{CC}
V _{ref}	1.5 V	50%V _{CC}
V _{OH1}	3 V	V _{CC}
V _{OL1}	GND	GND

- Notes:
1. Input waveform : PRR = 10 MHz, duty cycle 50%, t_r = 2.5 ns, t_f = 2.5 ns
 2. Waveform – A shows input conditions such that the output is "L" level when enabled by the output control.
 3. Waveform – B shows input conditions such that the output is "H" level when enabled by the output control.

Package Dimensions

As of January, 2002

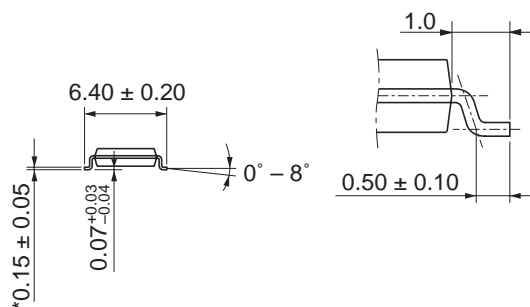
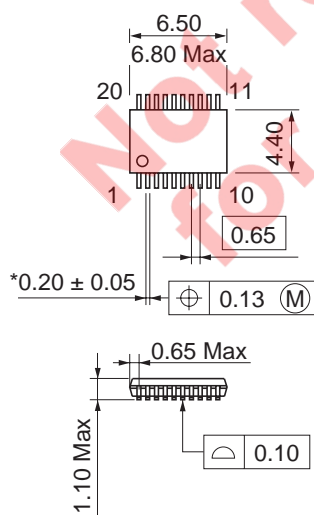
Unit: mm



Package Code	FP-20DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.31 g

As of January, 2002

Unit: mm



Package Code	TTP-20DAV
JEDEC	—
JEITA	—
Mass (reference value)	0.07 g

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Tel: <44> (1628) 585 100, Fax: <44> (1628) 585 900

Renesas Technology Europe GmbH

Dornacher Str. 3, D-85622 Feldkirchen, Germany
Tel: <49> (89) 380 70 0, Fax: <49> (89) 929 30 11

Renesas Technology Hong Kong Ltd.

7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2375-6836

Renesas Technology Taiwan Co., Ltd.

FL 10, #99, Fu-Hsing N. Rd., Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd.

26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China
Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.

1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
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